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Attorney Docket No. 1614.1082

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re F	Patent	App	olicatio	on of:			
Hideo	MIYA	KE	et al.				
Applic	ation	No.:		Group Art Unit:			
Filed:	Septe	emb	er 28,	Examiner: 2000			
For:				CONTROLLING A CACHE MEMORY TO INCREASE AN ACC ID A COMPUTER USING THE METHOD	CESS SPEED TO A MAIN		
				INFORMATION DISCLOSURE STATEMENT	RECEIVED		
Assist	ant Co	nmn	nissinr	ner for Patents	JUN 0 2 2003		
			C. 202		Technology Center 2100		
Sir:					Ų,		
inform It is re	ation quest	whiced the	ch the	th the duty of disclosure provisions of 37 CFR §1.56, there is h Examiner may consider material to the examination of the subject Examiner make this information of record if it is deemed mate in.	ect U.S. patent application.		
1. E	nclos	closures accompanying this Information Disclosure Statement are:					
	1	a.	[X]	Form PTO-1449.			
	1	b.	[X]	Copies of IDS citations.			
	1	c.	[]	An English language copy of a Search Report or Official Actio foreign application or the PCT International Search Report.	n from a counterpart		
	1	d.	[X]	English language translation (complete or relevant portion(s)) non-English language publication.	attached to each		
	1	<b>e</b> .	[X]	Explanations of Relevancy of References (ATTACHMENT 1(e concise explanation of each non-English publication.	e), hereto) for providing a		
	1	f.	[]	List of Copending Applications (ATTACHMENT 1(f), hereto).			
2. [	X] Ir	n ac	cordar ance c	nce with 37 CFR §1.98, a concise explanation of what is presently understood to be the of each non-English language publication is:			
				(Check appropriate Items 2a, 2b, 2c and/or 2d)			
	2	a.	[]	English language copy of the PCT International Search Report a counterpart foreign application indicating the degree of relevant	ise all non-English language publications were cited on the enclosed ge copy of the PCT International Search Report or the search report from oreign application indicating the degree of relevance found by the foreign S. Patent & Trademark Office's authorization in the Federal Register, Vol. nuary 17, 1992, at page 2031 (Reply to Comment 68).)		
	2	b.	[]	set forth in the application.	· .		

- 2c. [X] satisfied because an English language translation (complete or relevant portion(s)) is attached to each non-English language publication.
- 2d. [X] enclosed as Attachment 1(e), hereto.
- 3. No admission is made that the information cited in this Statement is, or is considered to be, material to patentability nor a representation that a search has been made (other than search report(s) from a counterpart foreign application or a PCT International Search Report, if submitted herewith). 37 CFR §§ 1.97(g) and (h).

Respectfully submitted,

STAAS & HALSEY LLP

Dated: September 28, 2000

700 Eleventh Street, N.W., Suite 500

Washington, D.C. 20001 Telephone: (202) 434-1500 Facsimile: (202) 434-1501 By:

J. Randall Beckers Registration No. 30,358



## EXPLANATIONS OF RELEVANCY OF REFERENCES

	ATTACHMENT 1(e)
ATTORNEY DOCKET NO.	APPLICATION NO.
1614.1082	
FIRST NAMED INVENTOR	-
Hideo MIYAKE et al.	
FILING DATE	GROUP ART UNIT
Sentember 28, 2000	

Reference AG discloses a semiconductor memory in which a random access memory (RAM) area is set for an arbitrary entry inside an arbitrary area of a cache memory. This shows a background technology of the present invention.

Reference AG discloses a data storage device which is provided in a data processor and can be used by the data processor as a cache memory or as a random access memory (RAM). This shows a background technology of the present invention.

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## INFORMATION DISCLOSURE STATEMENT w/FORM PTO-1449 AND REFERENCES

APPLICANT(S):

Hideo MIYAKE et al.

SERIAL NO:

09/671,117

CONFIRMATION NO.

8617

TITLE:

METHOD OF CONTROLLING A CACHE MEMORY TO INCREASE AN ACCESS SPEED TO A MAIN MEMORY, AND A COMPUTER USING THE

**METHOD** 

FILING DATE:

September 28, 2000

DOCKET NO:

1614.1082/HJS:sit

DUE DATE:

November 1, 2001.





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